

Excellent Integrated System Limited

Stocking Distributor

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Vishay/Siliconix SI1406DH-T1-GE3

For any questions, you can email us directly: sales@integrated-circuit.com





Si1406DH

Vishay Siliconix

N-Channel 20 V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)		
20	$0.065 \text{ at V}_{GS} = 4.5 \text{ V}$	3.9		
	0.075 at V _{GS} = 2.5 V	3.6		
	0.096 at V _{GS} = 1.8 V	3.2		

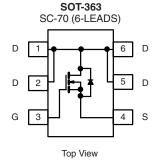
FEATURES

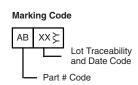
- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFETs: 1.8 V Rated
- Thermally Enhanced SC-70 Package
- Compliant to RoHS Directive 2002/95/EC



APPLICATIONS

- Load Switching
- PA Switch
- Level Switch





Ordering Information: Si1406DH-T1-E3 (Lead (Pb)-free)

Si1406DH-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS	Γ _A = 25 °C, unle	ss otherwise r	noted		
Parameter		Symbol	5 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	20		V
Gate-Source Voltage		V _{GS}	± 8		
Openhia	T _A = 25 °C	- I _D	3.9	3.1	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 85 °C		2.8	2.2	
Pulsed Drain Current		I _{DM}	10		Α
Continuous Source Current (Diode Conduction) ^a		I _S	1.4	0.9	
Martin of Branch Biratania	T _A = 25 °C	P _D	1.56	1.0	· w
Maximum Power Dissipation ^a	T _A = 85 °C		0.81	0.52	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Marrian Institut to Ambient	t ≤ 5 s	- R _{thJA}	60	80	°C/W
Maximum Junction-to-Ambient ^a	Steady State		100	125	
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	34	45	

Note:

a. Surface mounted on 1" x 1" FR4 board.

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Distributor of Vishay/Siliconix: Excellent Integrated System Limited

Datasheet of SI1406DH-T1-GE3 - MOSFET N-CH 20V 3.1A SC-70-6

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Si1406DH

Vishay Siliconix

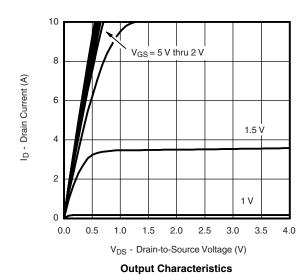


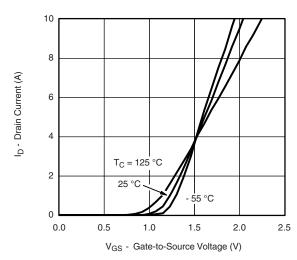
SPECIFICATIONS $T_J = 25$	°C, unless	otherwise noted					
Parameter	Symbol	Test Conditions Min. Typ		Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	0.45		1.2	V	
Gate-Body Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 8 V		± 100	nA		
7 O-t- Valtana Duais Ocument		V _{DS} = 20 V, V _{GS} = 0 V			1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 85 ^{\circ}\text{C}$			5	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	8			Α	
		$V_{GS} = 4.5 \text{ V}, I_D = 3.9 \text{ A}$		0.053	0.065		
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 2.5 \text{ V}, I_D = 3.6 \text{ A}$		0.062	0.075	Ω	
		V _{GS} = 1.8 V, I _D = 2 A		0.079	0.096		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 10 V, I _D = 3.9 A		11		S	
Diode Forward Voltage ^a	V_{SD}	I _S = 1.4 A, V _{GS} = 0 V		0.75	1.1	V	
Dynamic ^b							
Total Gate Charge	Qg			4.9	7.5	nC	
Gate-Source Charge	Q_{gs}	Q_{gs} $V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_D = 3.9 \text{ A}$		1.0			
Gate-Drain Charge	Q_{gd}			0.95		1	
Turn-On Delay Time	t _{d(on)}			27	41		
Rise Time	t _r	V_{DD} = 10 V, R_L = 20 Ω		47	71	ns	
Turn-Off Delay Time		$I_D\cong 0.5$ A, $V_{GEN}=4.5$ V, $R_g=6$ Ω		54	81		
Fall Time	t _f			29	44		
Source-Drain Reverse Recovery	t _{rr}	I _F = 1.4 A, dI/dt = 100 A/μs		35	60		

Notes:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





Transfer Characteristics

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a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

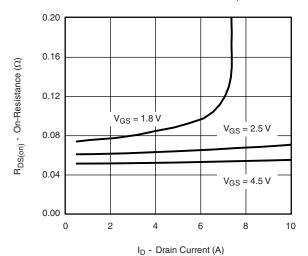




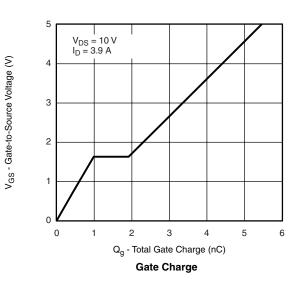
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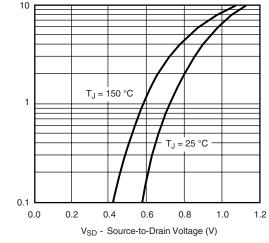
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

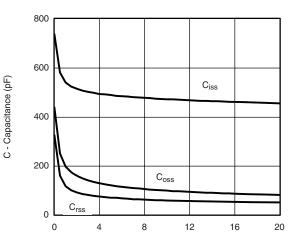


On-Resistance vs. Drain Current



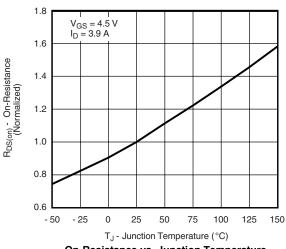


Source-Drain Diode Forward Voltage

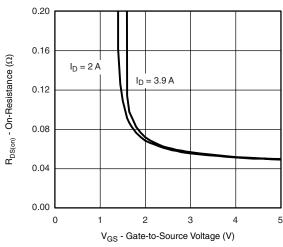


V_{DS} - Drain-to-Source Voltage (V)





On-Resistance vs. Junction Temperature



On-Resistance vs. Gate-to-Source Voltage

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Is - Source Current (A)

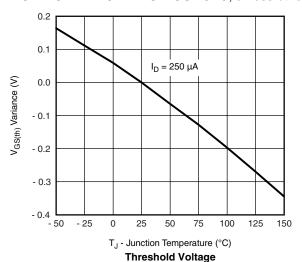


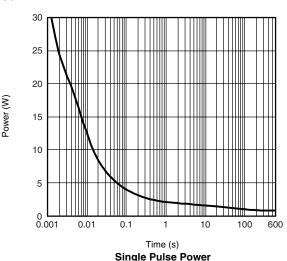
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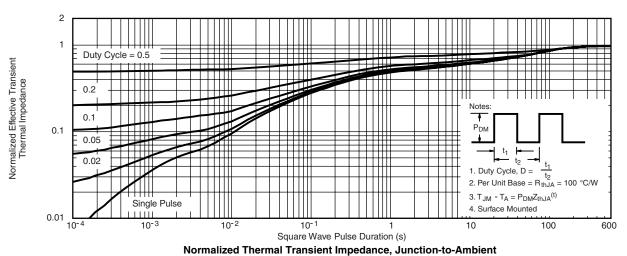
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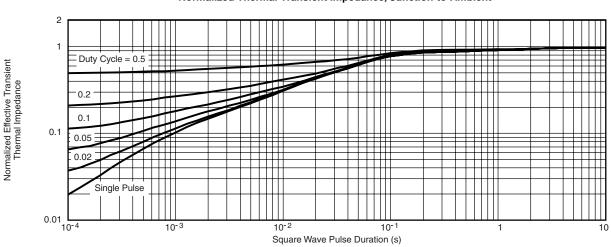
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted









Normalized Thermal Transient Impedance, Junction-to-Foot

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?70684.



Distributor of Vishay/Siliconix: Excellent Integrated System Limited

Datasheet of SI1406DH-T1-GE3 - MOSFET N-CH 20V 3.1A SC-70-6

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